

homogenizestudy

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Blue lines: MCNPX. Green lines: VBUDSII.

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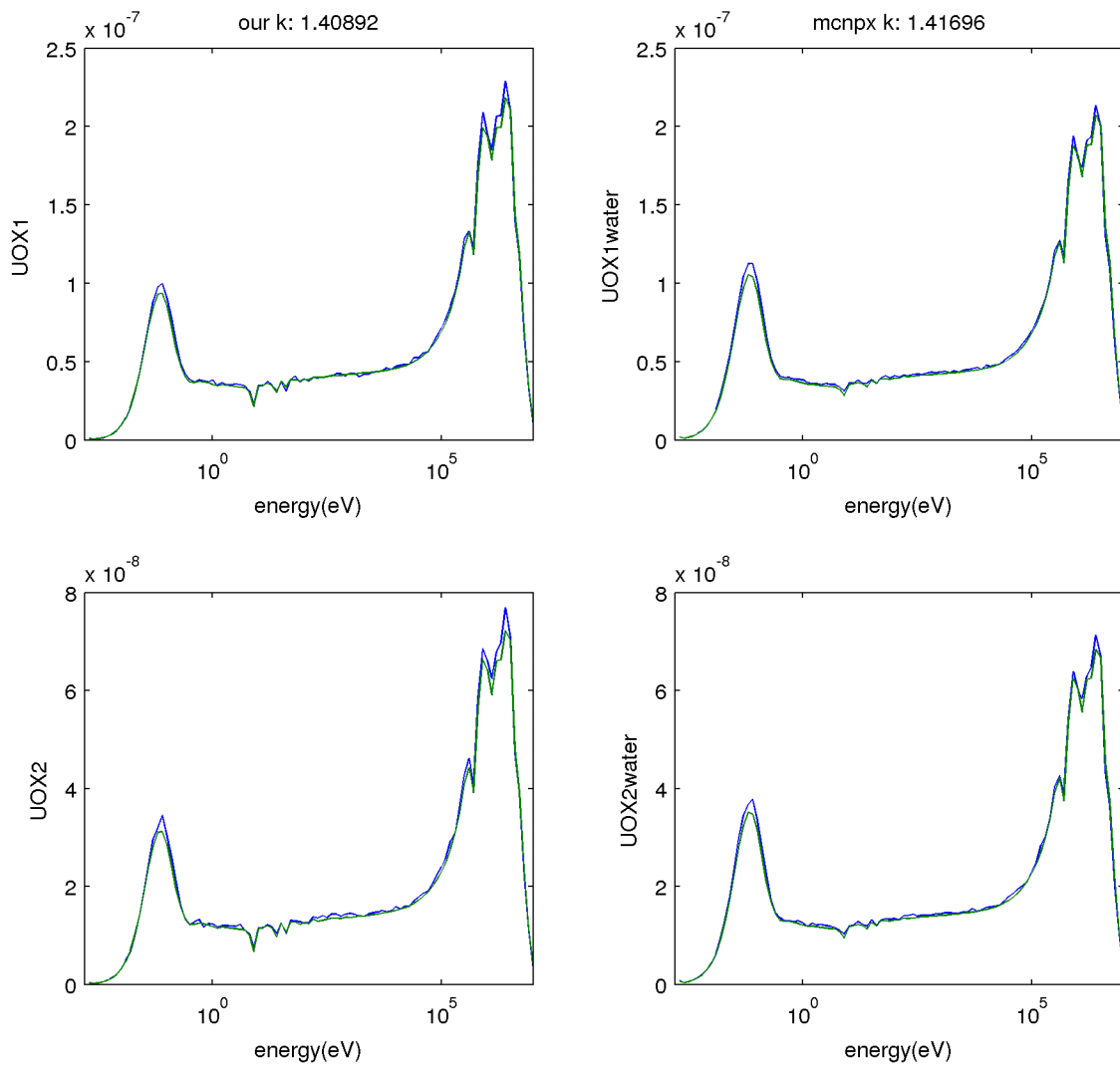


Figure 1: Both fuel pins are the same enriched UOX. Method unmodified..

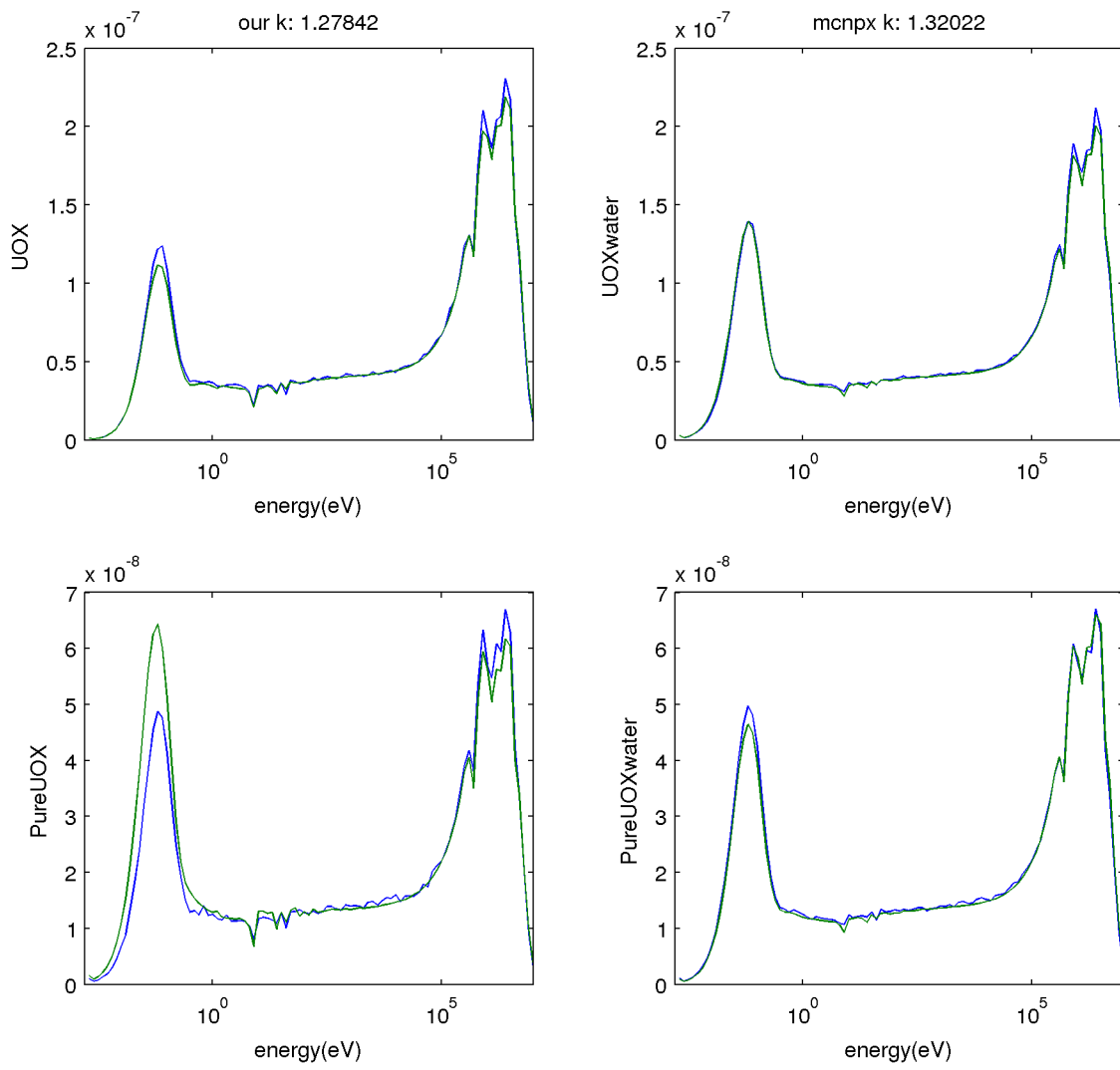


Figure 2: THERMAL 1. Pin 1: 3% enriched UOX, Pin 2: 0% enriched UOX. Method unmodified. .

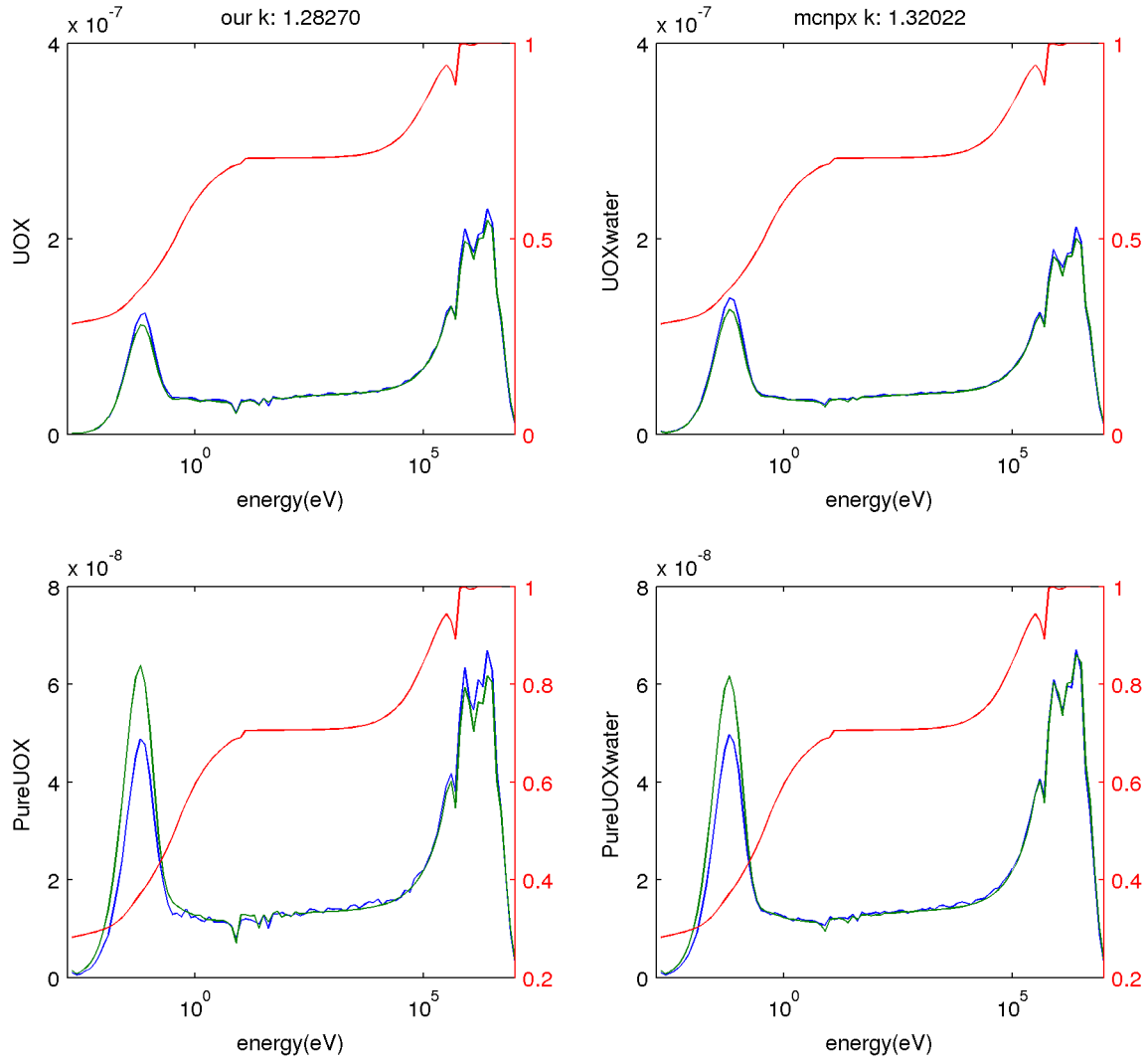


Figure 3: THERMAL 1. Pin 1: 3% enriched UOX, Pin 2: 0% enriched UOX. Homogeneity: original scheme. . In this method, a single homogenization factor is used for all cells. The multiplication factor is slightly better using this simple homogeneity method, but the thermal peak in the pure UO₂ moderator increases, whereas it had been correct before using homogenization.

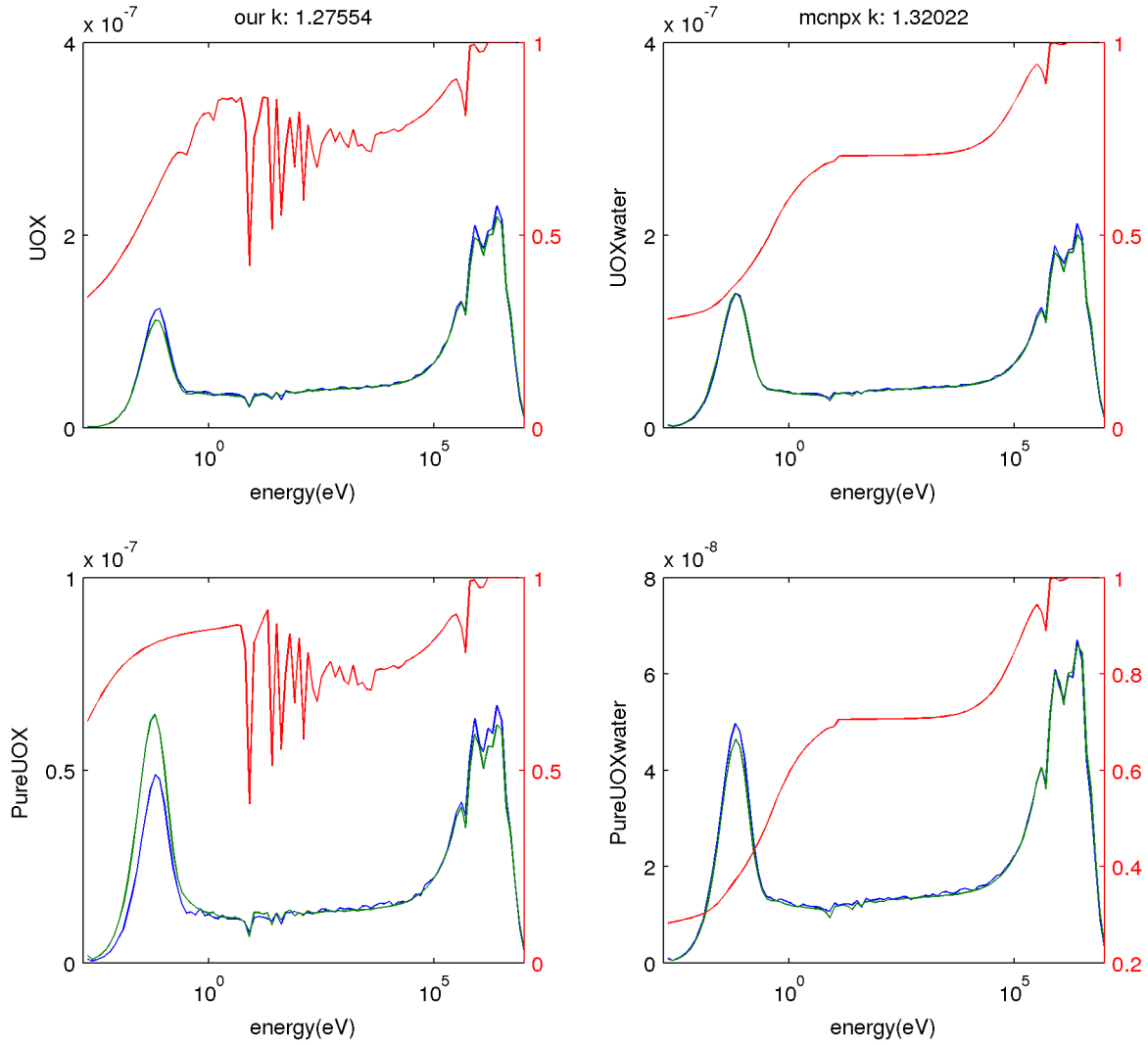


Figure 4: THERMAL 1. Pin 1: 3% enriched UOX, Pin 2: 0% enriched UOX. Homogeneity: 2nd 'indiv' scheme. . In this case, each cell has its own homogenization factor, and the resulting PI is obtained in a mannner different than that used for Figure 3. The multiplication factor is worse than for the simple homogeneity method, but the flux in the pure UOX thermal now again matches the MCNPX result (as it did when not doing homogenization). Note that this output was generated using the two parameters for homogeneity that yielded the least error.

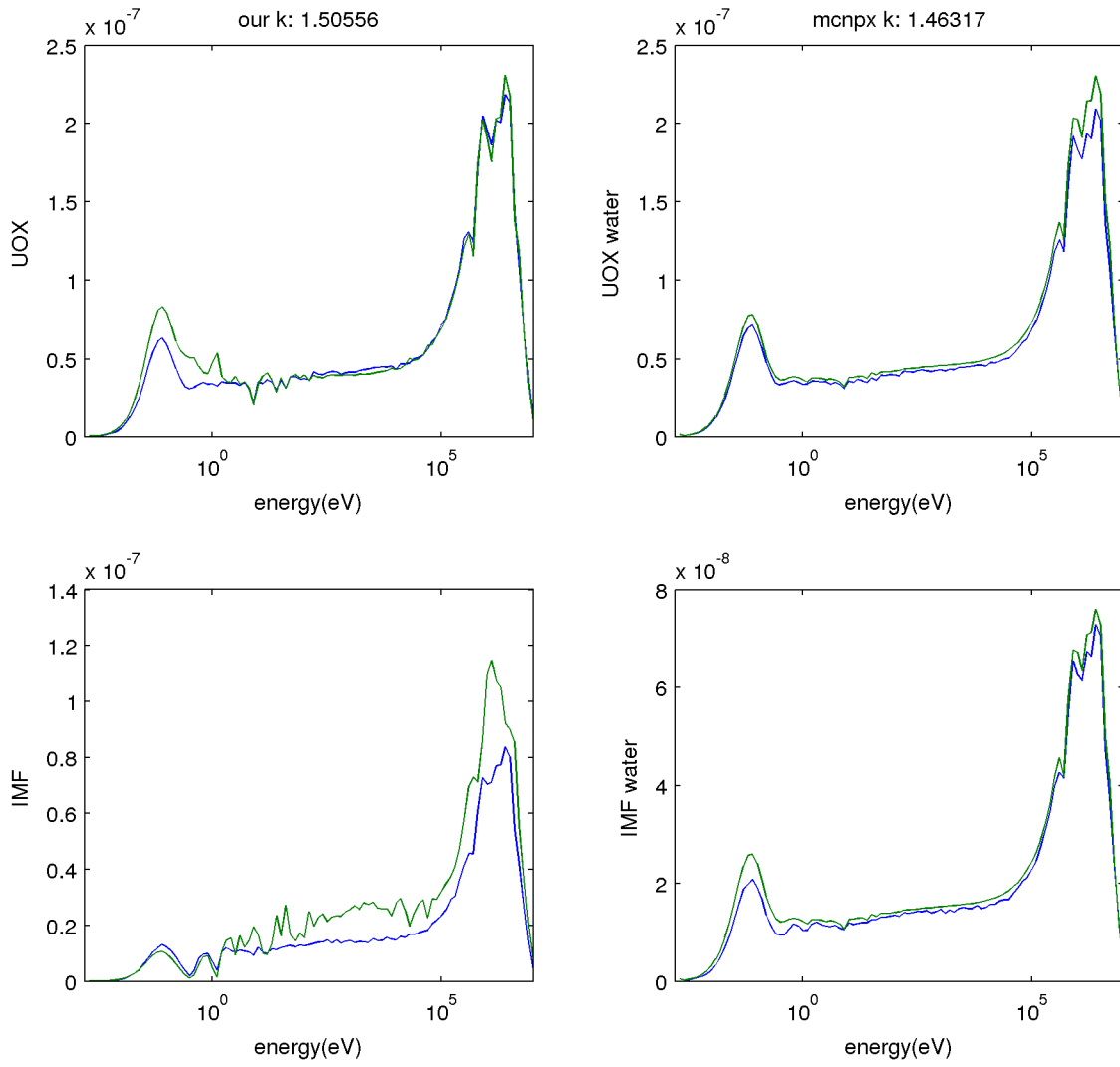


Figure 5: THERMAL 2. Pin 1: 3% enriched UOX, Pin 2: IMF. Method unmodified. .

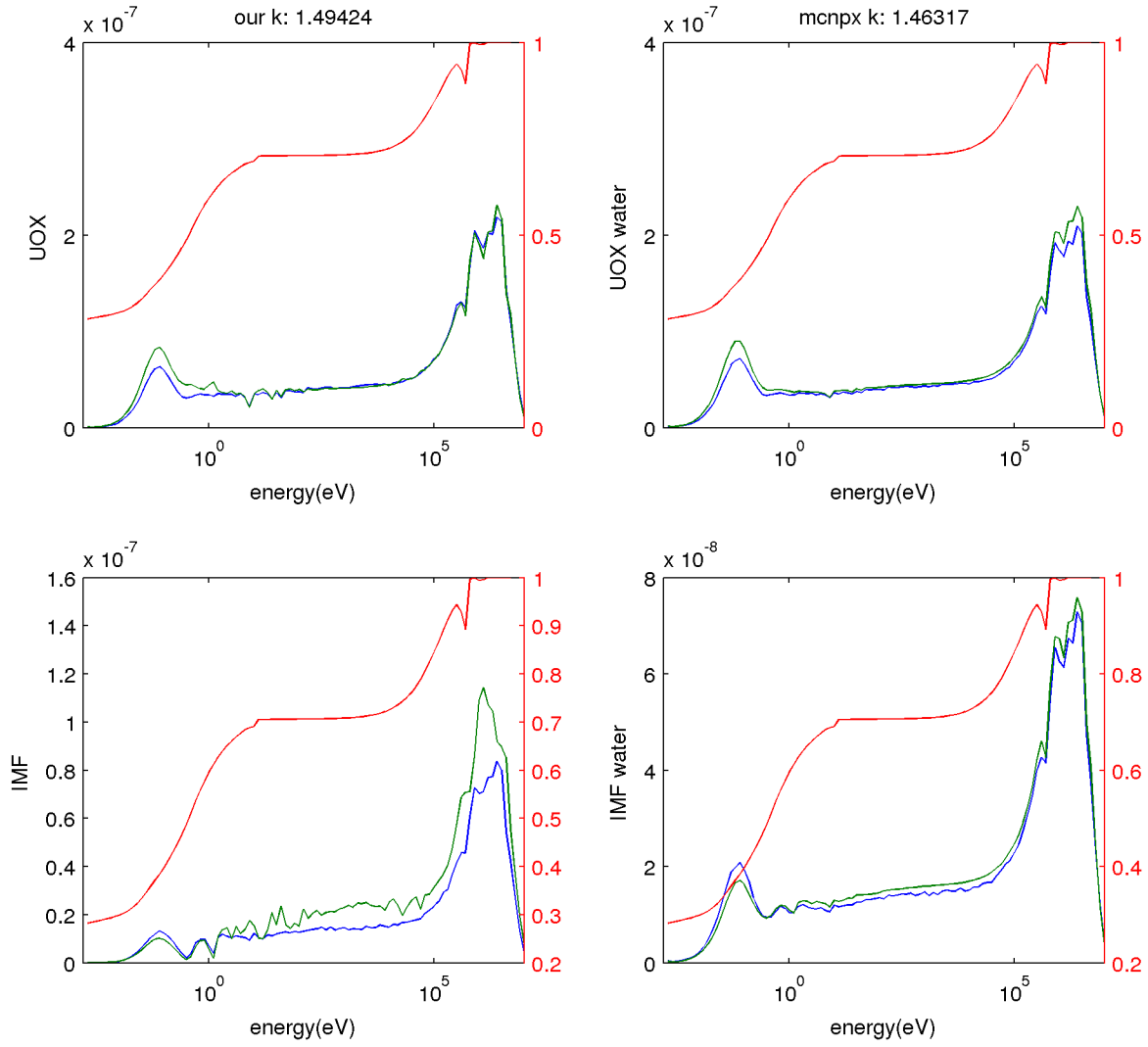


Figure 6: THERMAL 2. Pin 1: 3% enriched UOX, Pin 2: IMF. Homogeneity: original scheme. . Again, one homogenization factor is used for all cells. The multiplication factor improves, but the flux does not change.

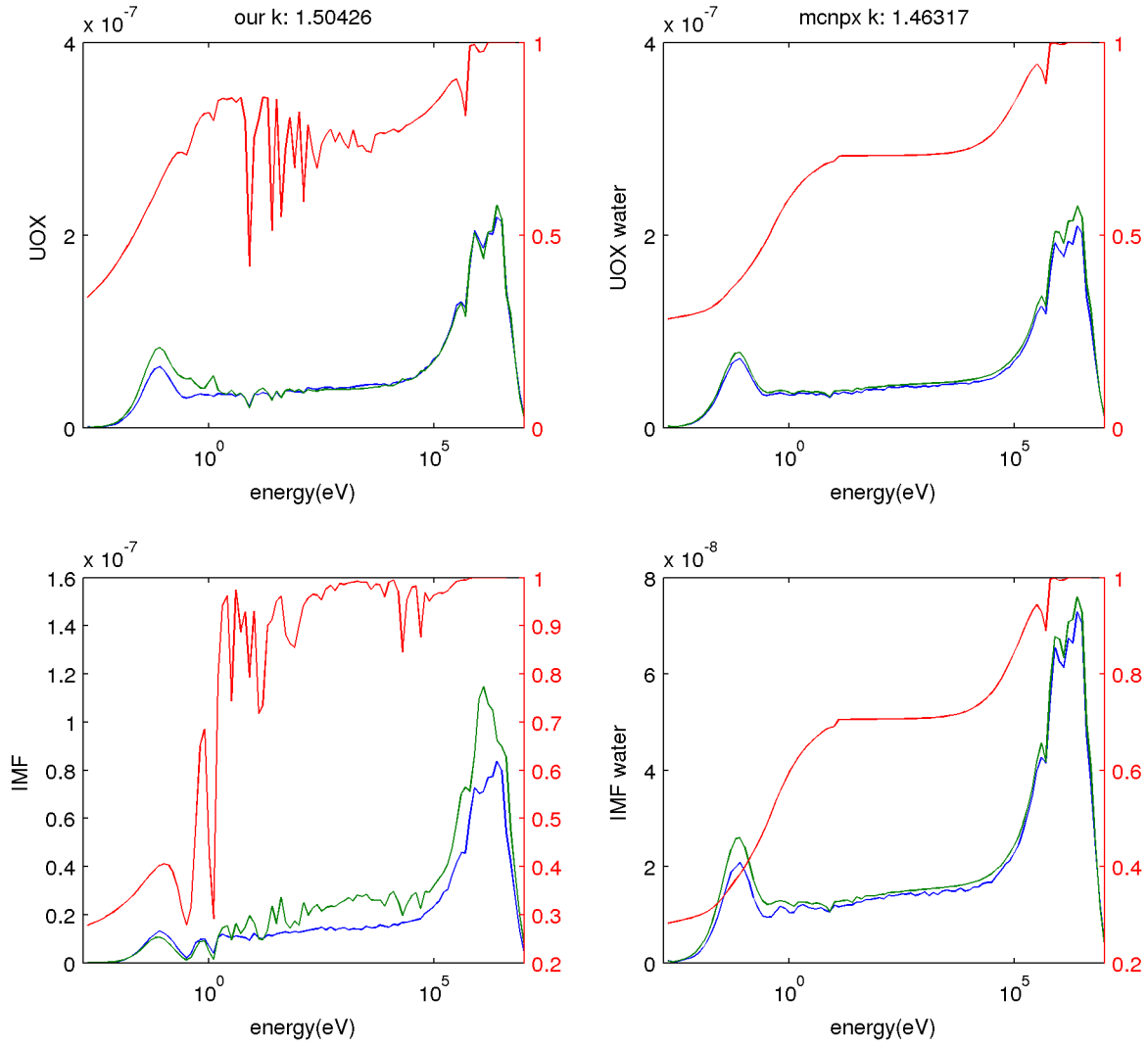


Figure 7: THERMAL 2. Pin 1: 3% enriched UOX, Pin 2: IMF. Homogeneity: 2nd 'indiv' scheme. . Multiplication factor gets worse and the flux does not improve. Note that this output was generated using the two parameters for homogeneity that yielded the least error.

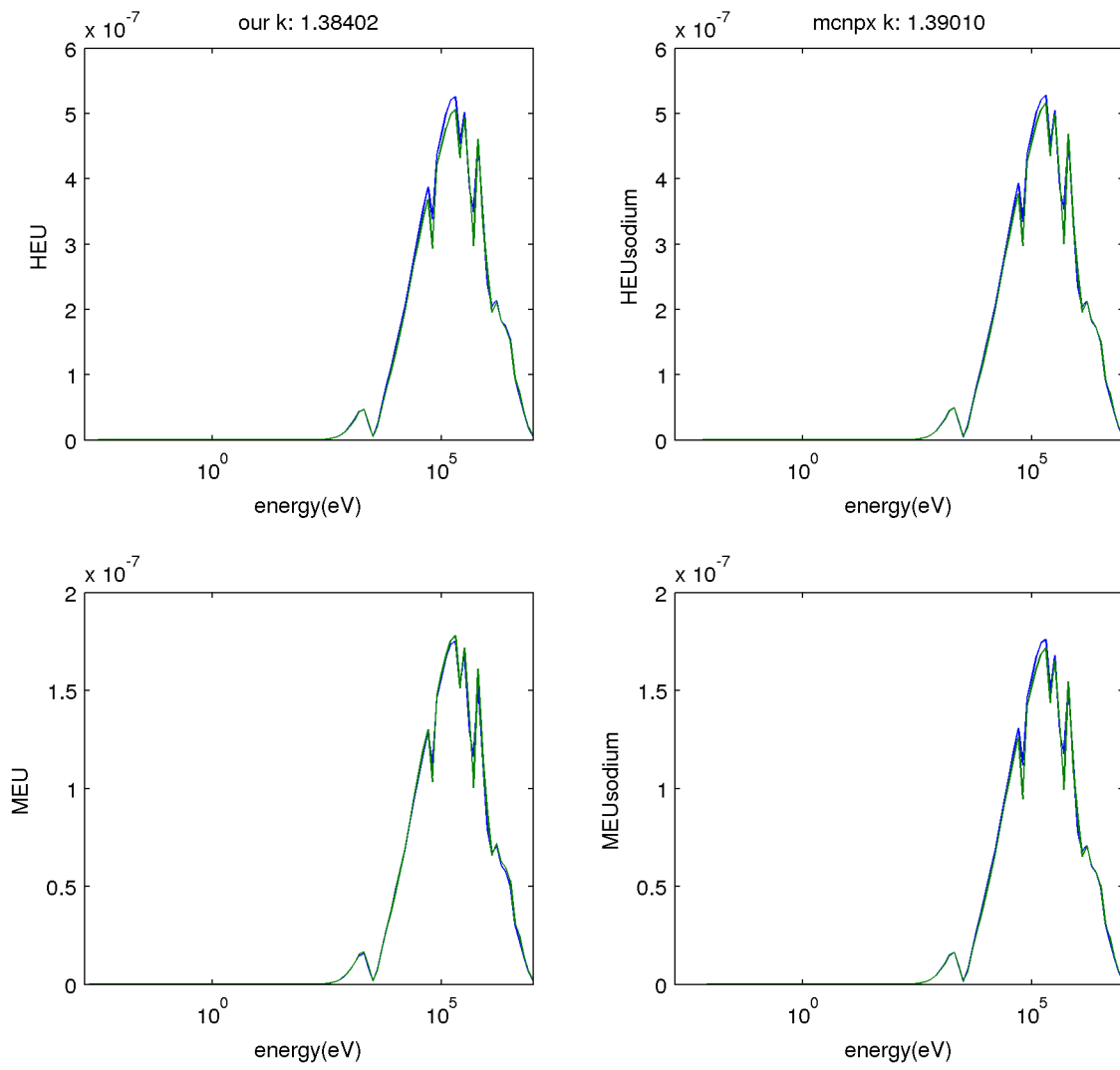


Figure 8: FAST 1. Pin 1: 24% enriched UOX, Pin 2: 12% enriched UOX Method unmodified. .

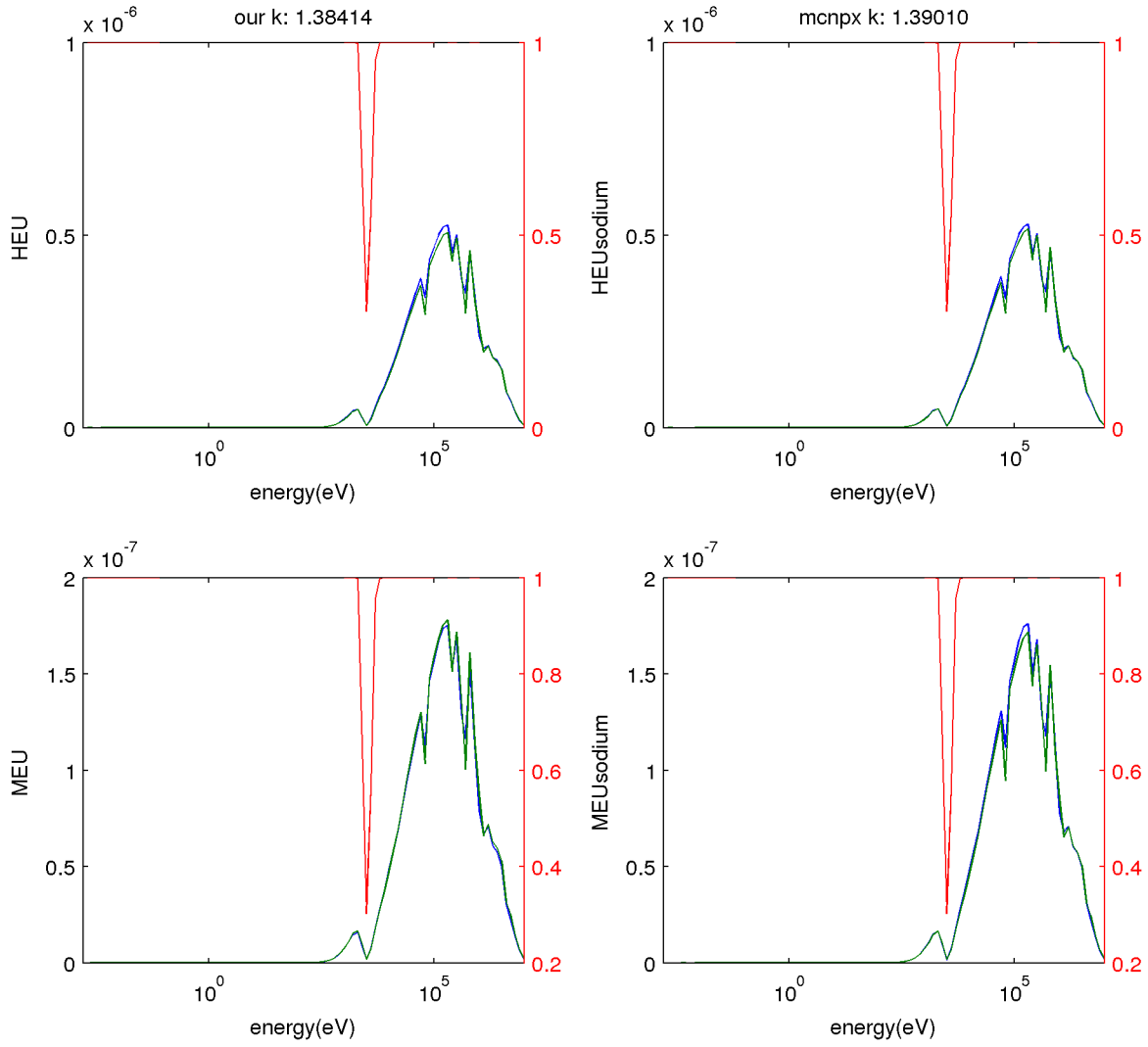


Figure 9: FAST 1. Pin 1: 24% enriched UOX, Pin 2: 12% enriched UOX Homogeneity: original scheme. . As expected, homogeneity has no appreciable effect on fast reactor results.

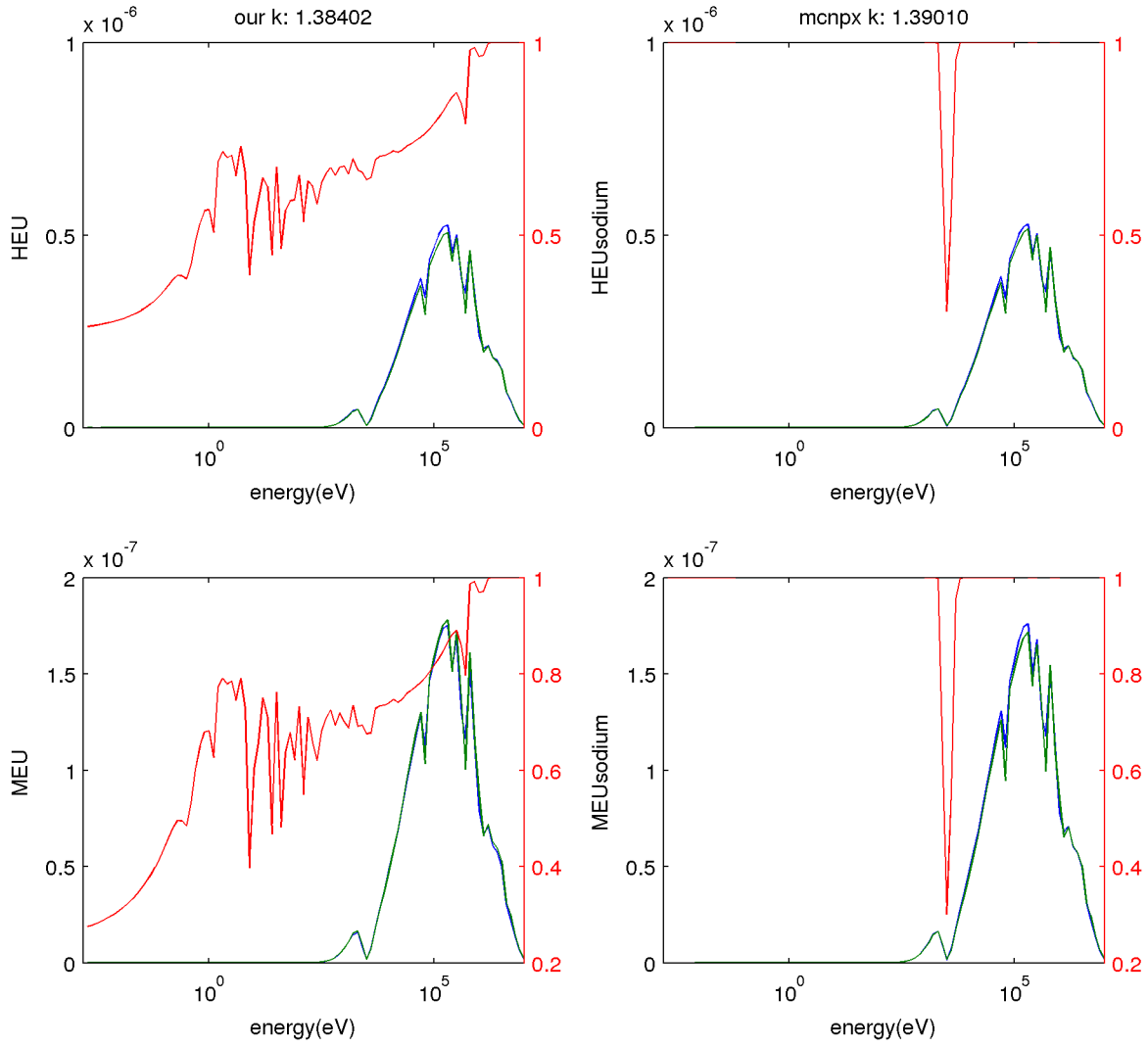


Figure 10: FAST 1. Pin 1: 24% enriched UOX, Pin 2: 12% enriched UOX Homogeneity: 2nd 'indiv' scheme. .

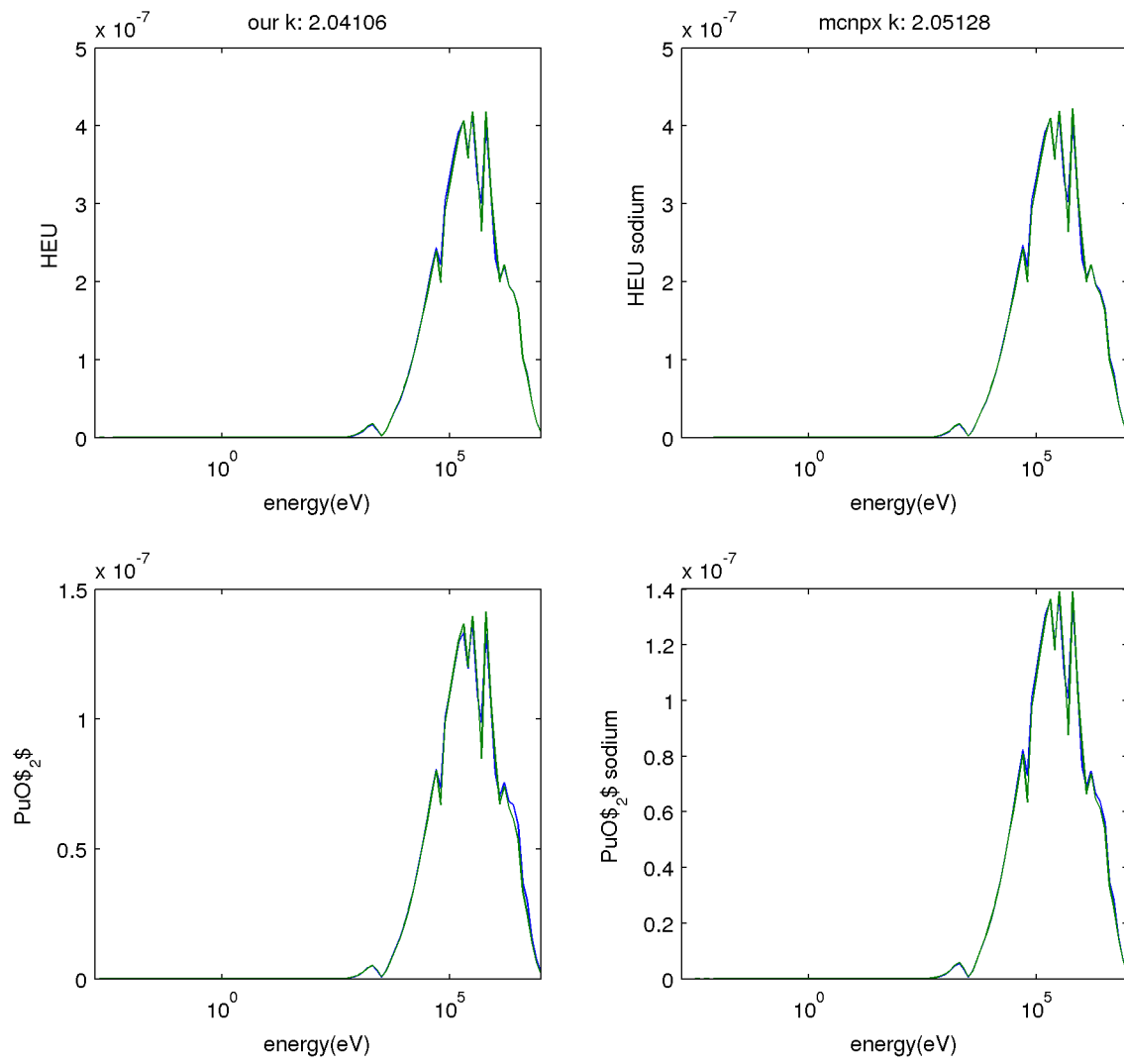


Figure 11: FAST 2. Pin 1: 24% enriched UOX, Pin 2: $\text{Pu}(239)\text{O}_2$. Method unmodified. .

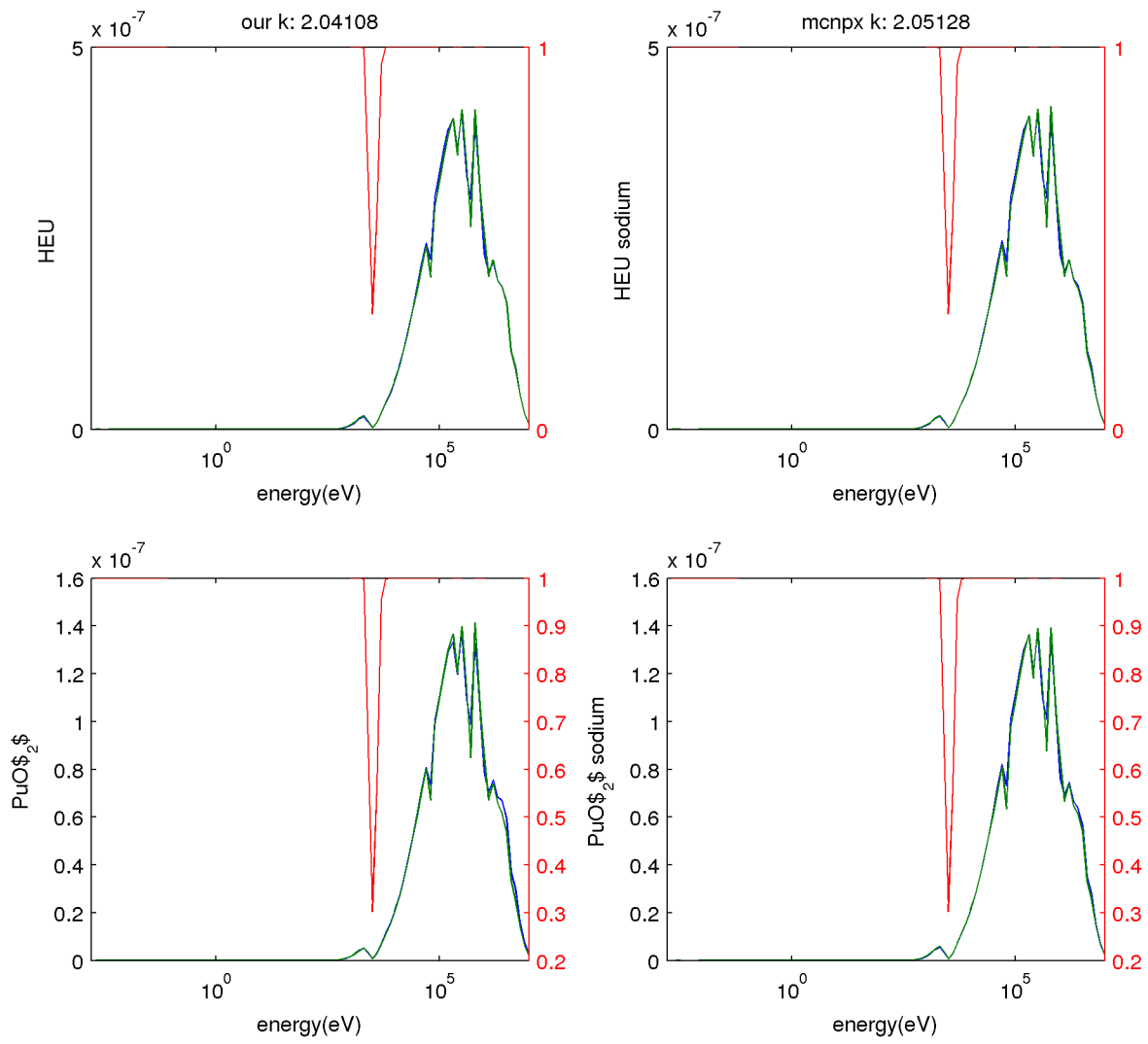


Figure 12: FAST 2. Pin 1: 24% enriched UOX, Pin 2: Pu(239)O₂. Homogeneity: original scheme. .

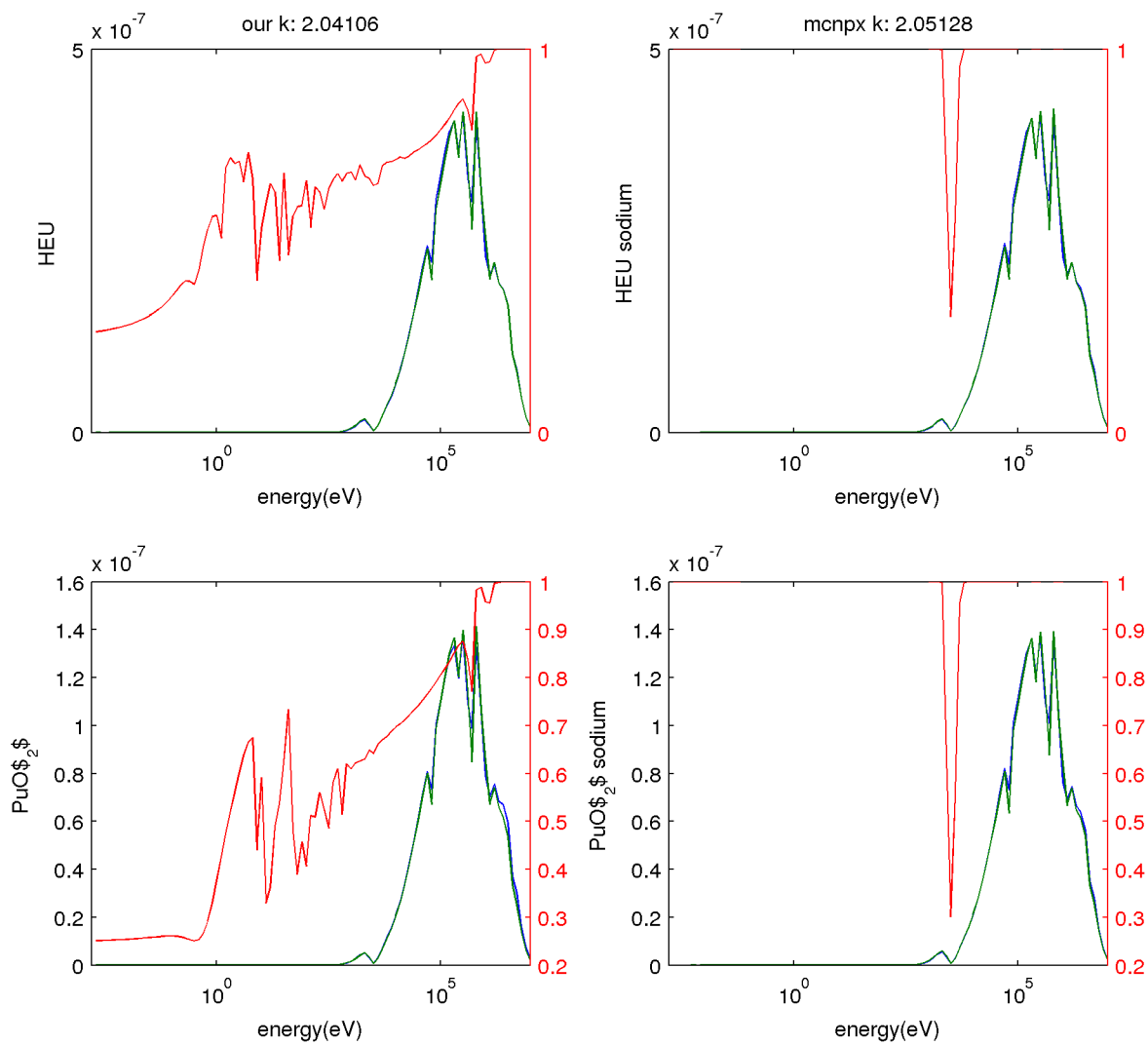


Figure 13: FAST 2. Pin 1: 24% enriched UOX, Pin 2: Pu(239)O₂. Homogeneity: 2nd 'indiv' scheme. .